DESCRIPTION

The SPN2302 is the N-Channel logic enhancement mode power field effect transistors are produced using high cell density, DMOS trench technology.

This high density process is especially tailored to minimize on-state resistance.

These devices are particularly suited for low voltage application such as cellular phone and notebook computer power management and other battery powered circuits, and low in-line power loss are needed in a very small outline surface mount package.

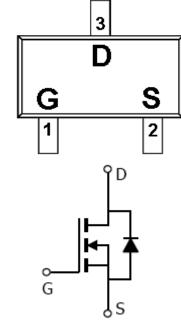
APPLICATIONS

- Power Management in Note book
- Portable Equipment
- Battery Powered System
- DC/DC Converter
- Load Switch
- DSC
- LCD Display inverter

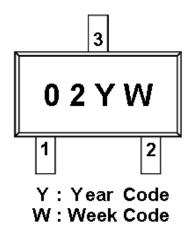
FEATURES

- 20V/3.6A, RDS(ON)= $80m\Omega@VGS=4.5V$
- 20V/3.1A,RDS(ON)= $95m\Omega@VGS=2.5V$
- Super high density cell design for extremely low RDs (ON)
- Exceptional on-resistance and maximum DC current capability
- ♦ SOT-23-3L package design

PIN CONFIGURATION(SOT-23-3L)



PART MARKING





PIN DESCRIPTION		
Pin	Symbol	Description
1	G	Gate
2	S	Source
3	D	Drain

ORDERING INFORMATION

Part Number	Package	Part Marking
SPN2302S23RGB	SOT-23-3L	02

Week Code : $A \sim Z(1 \sim 26)$; $a \sim z(27 \sim 52)$

X SPN2302S23RGB : Tape Reel ; Pb – Free ; Halogen – Free

ABSOULTE MAXIMUM RATINGS

(TA=25°C Unless otherwise noted)

Parameter		Symbol	Typical	Unit	
Drain-Source Voltage		Vdss	20	V	
Gate –Source Voltage		VGSS	±12	V	
Continuous Drain Current/Tr-150°C)	TA=25°C	In	3.2	А	
Continuous Drain Current(TJ=150°C)	TA=70°C	ID	2.6	A	
Pulsed Drain Current		Ідм	10	А	
Continuous Source Current(Diode Conduction)		Is	1.6	А	
Demon Dissingtion	TA=25°C	Do	1.25	X 7	
Power Dissipation	Ta=70°C	PD	0.8	W	
Operating Junction Temperature		τT	-55/150	°C	
Storage Temperature Range		Tstg	-55/150	°C	
Thermal Resistance-Junction to Ambient		Rөја	100	°C/W	

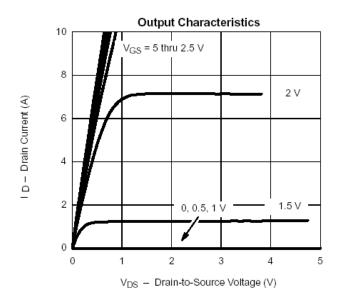


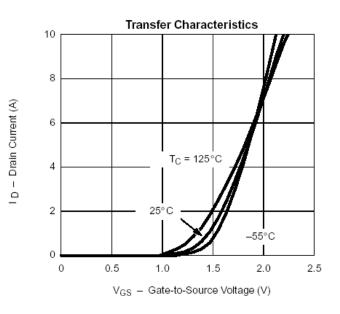
ELECTRICAL CHARACTERISTICS

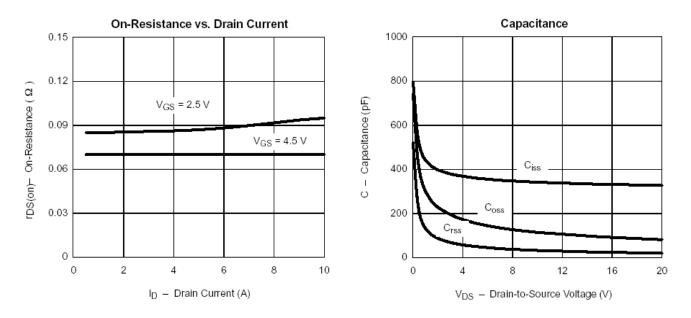
(TA=25°C Unless otherwise noted)

Parameter	Symbol	Conditions	Min.	Тур	Max.	Unit
Static						
Drain-Source Breakdown Voltage	V(BR)DSS	Vgs=0V,Id=250uA	20			V
Gate Threshold Voltage	VGS(th)	VDS=VGS,ID=250uA	0.45		1.2	V
Gate Leakage Current	Igss	VDS=0V,VGS=±12V			±100	nA
Zero Gate Voltage Drain Current		VDS=20V,VGS=0V			1	uA
	Idss	Vds=20V,Vgs=0V Tj=55°C			10	
On-State Drain Current	ID(on)	$V_{DS} \ge 5V, V_{GS} = 4.5V$	6			A
	ID(on)	$V_{DS} \ge 5V, V_{GS} = 2.5V$	4			
Drain-Source On-Resistance	RDS(on)	VGS=4.5V,ID=3.6A		0.050	0.080	Ω
		VGS=2.5V,ID=3.1A		0.070	0.095	
Forward Transconductance	gfs	VDS=5V,ID=3.6A		10		S
Diode Forward Voltage	Vsd	Is=1.6A,VGs=0V		0.85	1.2	V
Dynamic						
Total Gate Charge	Qg			5.4	10	nC
Gate-Source Charge	Qgs	$V_{DS}=10V, V_{GS}=4.5V$ $I_{D}=3.6A$		0.65		
Gate-Drain Charge	Qgd	ID-3.0A		1.4		
Input Capacitance	Ciss			340		
Output Capacitance	Coss	VDS=10V,VGS=0V f=1MHz		115		pF
Reverse Transfer Capacitance	Crss			33		
Turn-On Time	td(on)			12	25	nS
	tr	$V_{DD}=10V,RL=5.5\Omega$		36	60	
Turn-Off Time	td(off)	ID=3.6A,VGEN=4.5V RG=6 Ω		34	60	
	tf]		10	25	

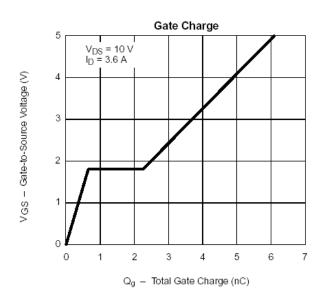
TYPICAL CHARACTERISTICS

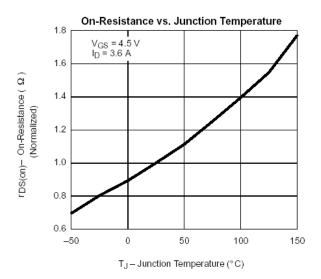




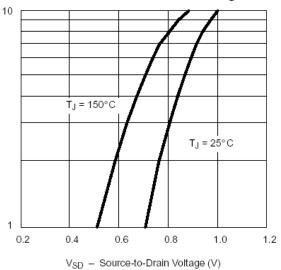


TYPICAL CHARACTERISTICS

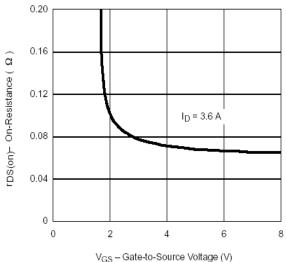




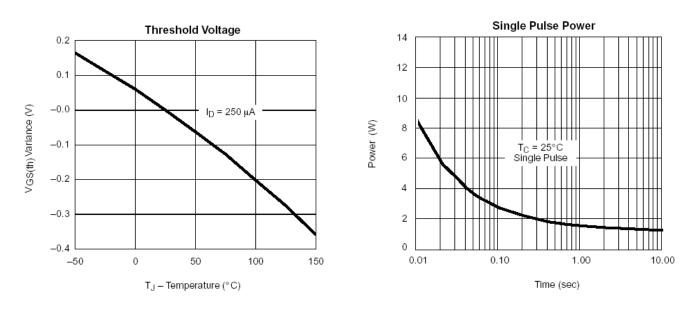
Source-Drain Diode Forward Voltage

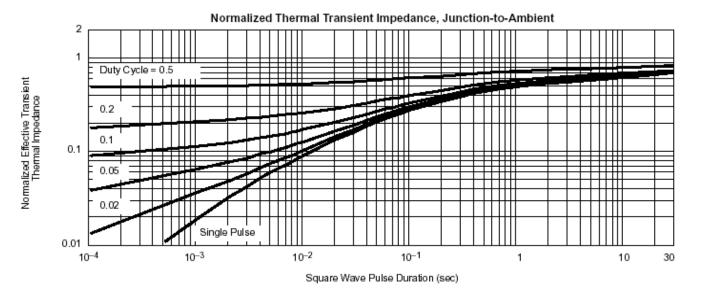


On-Resistance vs. Gate-to-Source Voltage



TYPICAL CHARACTERISTICS







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